

TECHNICAL SPECIFICATION

**Photovoltaic (PV) modules – Test methods for the detection of potential-induced degradation –
Part 1: Crystalline silicon**



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INTERNATIONAL ELECTROTECHNICAL COMMISSION

**PHOTOVOLTAIC (PV) MODULES –
TEST METHODS FOR THE DETECTION
OF POTENTIAL-INDUCED DEGRADATION –****Part 1: Crystalline silicon****FOREWORD**

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IEC TS 62804-1 has been prepared by IEC technical committee 82: Solar photovoltaic energy systems. It is a Technical Specification.

This second edition cancels and replaces the first edition published in 2015. This edition constitutes a technical revision.

This edition includes the following significant technical changes with respect to the previous edition:

- a) A procedure specifically for measuring PID-polarization was added.
- b) A procedure specifically for measuring the extent of recovery of PID-polarization was added.

The text of this Technical Specification is based on the following documents:

Draft	Report on voting
82/2366/DTS	82/2424/RVDTS

Full information on the voting for its approval can be found in the report on voting indicated in the above table.

The language used for the development of this Technical Specification is English.

This document was drafted in accordance with ISO/IEC Directives, Part 2, and developed in accordance with ISO/IEC Directives, Part 1 and ISO/IEC Directives, IEC Supplement, available at www.iec.ch/members_experts/refdocs. The main document types developed by IEC are described in greater detail at www.iec.ch/publications.

A list of all parts in the IEC 62804 series, published under the general title *Photovoltaic (PV) modules – Test methods for the detection of potential-induced degradation*, can be found on the IEC website.

The committee has decided that the contents of this document will remain unchanged until the stability date indicated on the IEC website under webstore.iec.ch in the data related to the specific document. At this date, the document will be

- reconfirmed,
- withdrawn, or
- revised.

INTRODUCTION

This part of IEC TS 62804 is for testing and measuring the resistance of crystalline silicon photovoltaic (PV) modules to stresses that cause potential-induced degradation (PID). The applied stresses, mainly system voltage, manifest in different degradation mechanisms depending on the module technology. A series of Technical Specifications is therefore developed to establish tests for measuring PID in different photovoltaic module technologies.

IEC TS 62804-1 defines test methods for measuring PID in crystalline silicon PV modules.

IEC TS 62804-1-1 defines test methods for measuring PID delamination in crystalline silicon PV modules.

IEC TS 62804-2 defines test methods for measuring PID in thin-film PV modules.

Additional Technical Specifications in the series may be introduced in the future for emerging module technologies or related degradation modes.

Voltage potential that exists between the active circuit and the grounded module surfaces can lead to module degradation by multiple mechanisms including ionic transport in the encapsulant, superstrate, or substrate, hot carriers in the cell, redistribution of charges that degrade the active layer of the cell or its surfaces, failure of adhesion at interfaces, and corrosion of module components. These degradation mechanisms in crystalline silicon photovoltaic modules caused by voltage stress and promoted by high temperature and humidity include potential-induced degradation, polarization, electrolytic corrosion, and electrochemical corrosion. They are most active in wet or damp environments, and in environments prone to soiling of modules with conductive, acidic, caustic, or ionic species that lead to increased conduction on the module surfaces. In the field, modules have been observed to degrade in positive as well as negative polarity strings depending on the cell construction, module materials, and design. The testing in this document therefore specifies the evaluation of the effects of voltage stress in the PV system mounting polarities permitted by the module manufacturer's documented specifications. Some crystalline silicon module designs undergoing system voltage bias stress have shown degradation manifested by junction failure, leading to changes in the reverse-bias breakdown characteristics and a resulting degradation in safety because of the increased potential for development of hot spots in the module. This document defines methods to measure the ability of a module to withstand degradation from system voltage effects that manifest in the relatively short term, or what is categorized as an infant failure, based on inherent sensitivities existing in a new module.

The stress-test levels in this document have not been related to those of the natural environment. Module types undergoing damp heat chamber testing with a 60 °C temperature and 85 % relative humidity stress level, with the temperature, humidity, and bias voltage ramped simultaneously at the start of a 96 h stress test without a PID recovery procedure, were found resistant to PID-shunting in outdoor tests in Florida, USA. However, to improve reproducibility, test details including environmental chamber temperature and humidity ramps and tolerances have been tightened, which very significantly reduces the total stress applied and invalidates the correspondences previously found. The relevance to real outdoor stress conditions of the test contained herein using foil as the ground conductor is also not proven. Alternative levels beyond the basic stress levels in this document are thus included.

It is known that variability in manufacturing processes can affect the susceptibility of modules to system voltage stress. Retesting of module samples by the test protocols contained herein, internal quality assurance programs, or external audits will aid in verifying not only the durability of the design of the module to system voltage stress, but also the effects of variability of the materials and manufacturing processes.

In this second edition, specific tests for PID-polarization and its recovery have been added. The factor of ultraviolet light has been included in the test to achieve a more representative test and therefore more meaningful results.

PHOTOVOLTAIC (PV) MODULES – TEST METHODS FOR THE DETECTION OF POTENTIAL-INDUCED DEGRADATION –

Part 1: Crystalline silicon

1 Scope

This part of IEC 62804 defines procedures to evaluate the durability of crystalline silicon photovoltaic (PV) modules to the effects of short-term high-voltage stress, primarily potential-induced degradation (PID). Three test methods are given. The first type, which has two variations, is conducted in the dark and is primarily designed for assessing PID-shunting. The second type, which also has two variations, incorporates the factor of ultraviolet light and is intended for assessing PID-polarization. A separate test for the recovery of PID polarization under ultraviolet light is also included.

The testing in this document is designed for crystalline silicon PV modules with silicon cells having passivating dielectric layers, for degradation mechanisms involving mobile ions influencing the electric field over the silicon semiconductor or electronically interacting with the silicon semiconductor. This document is not intended for evaluating modules with thin-film technologies, tandem, or heterojunction devices but can be used for guidance.

The actual durability of modules to system voltage stress depends on the environmental conditions under which they are operated and the voltage potential in the module relative to earth (ground). These tests are intended to assess PV module sensitivity to PID irrespective of actual stresses under operation in different climates and systems.

2 Normative references

The following documents are referred to in the text in such a way that some or all of their content constitutes requirements of this document. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

IEC 60068-2-78:2012, *Environmental testing – Part 2-78: Tests – Test Cab: Damp heat, steady state*

IEC 61215-1, *Terrestrial photovoltaic (PV) modules – Design qualification and type approval – Part 1: Test requirements*

IEC 61215-2:2021, *Terrestrial photovoltaic (PV) modules – Design qualification and type approval – Part 2: Test procedures*

IEC 61724-1, *Photovoltaic system performance – Part 1: Monitoring*

IEC 61730-2, *Photovoltaic (PV) module safety qualification – Part 2: Requirements for testing*

IEC TS 61836, *Solar photovoltaic energy systems – Terms, definitions and symbols*